

Electronic Supplementary Information for

# Tracer diffusion of $^{96}\text{Zr}$ and $^{134}\text{Ba}$ in polycrystalline $\text{BaZrO}_3$

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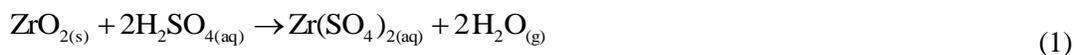
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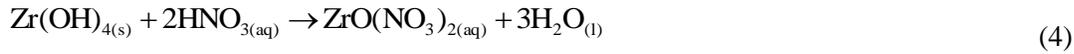
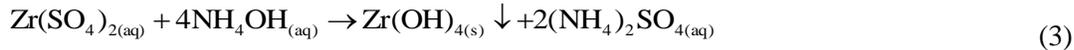
## 1 Deposition of $\text{ZrO}_2$ films

In order to synthesize a film of  $^{96}\text{ZrO}_2$  on the BZ pellets the following procedure was developed. Appropriate amount of the  $\text{ZrO}_2$  precursor was suspended in excess of concentrated 98%  $\text{H}_2\text{SO}_4$  in a covered glass and heated to 200 °C on a magnetic stirrer. After complete dissolution of the precursor (reaction (1)), the resulting slightly yellow transparent solution was slowly evaporated at 200 °C over excess amount of NaOH solution resulting in hydrated  $\text{Zr}(\text{SO}_4)_2$ . The NaOH solution was used to reduce fuming and collect most of the acidic vapour. The white crystalline solid was carefully dried on a hotplate in order to remove traces of  $\text{H}_2\text{SO}_4$  and then cooled to room temperature.  $\text{Zr}(\text{SO}_4)_2$  was then dissolved in deionized water giving a solution with pH~1-2. The acidic solution was neutralized with 28%  $\text{NH}_4\text{OH}$  until a white fluffy solid precipitated at pH~8 as described by reaction (3). The mixture was carefully dried on a hotplate at 80 °C resulting in a white  $\text{Zr}(\text{OH})_4$  amorphous solid. The reaction product  $\text{Zr}(\text{OH})_4$  was gently mixed with 65%  $\text{HNO}_3$  until complete dissolution as shown in reaction (4). Finally, the solvent was evaporated at 110 °C giving white  $\text{ZrO}(\text{NO}_3)_2 \cdot x\text{H}_2\text{O}$  crystals. This product was dried at 80 °C and used further.

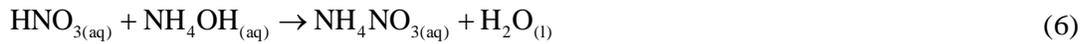
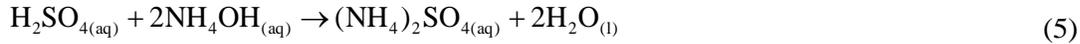


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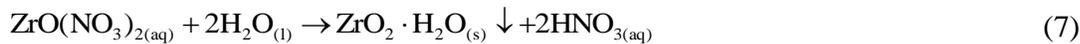
<sup>1</sup> Corresponding author: grande@ntnu.no



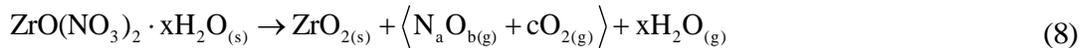
In addition to the process above, side reactions (5) and (6) occurred producing minor amount of ammonium sulfate and ammonium nitrate, which affected the phase purity of tracer layer produced by the procedure,



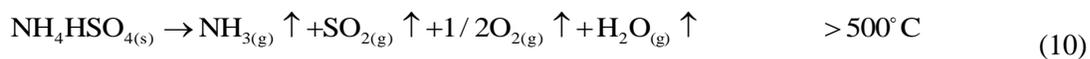
The main product  $\text{ZrO}(\text{NO}_3)_2 \cdot x\text{H}_2\text{O}$  was dissolved in deionized water (0.05 M) and drop casted on  $\text{BaZrO}_3$  pellets at 90 °C. The coated pellets were carefully dried at 150 °C giving a white layer of  $\text{ZrO}(\text{NO}_3)_2 \cdot x\text{H}_2\text{O}$ . Note that the solution had to be used as soon as possible due to the hydrolysis of  $\text{ZrO}(\text{NO}_3)_2 \cdot x\text{H}_2\text{O}$  in water according to reaction (7)



The  $\text{ZrO}(\text{NO}_3)_2 \cdot x\text{H}_2\text{O}$  layer was decomposed at 800 °C for 3 h in flowing  $\text{N}_2$  resulting in a white, dense and homogeneous layer of  $\text{ZrO}_2$  (~1-1.5 μm), reaction (8).



In addition to the main reaction (8) above, side reactions due to the minor products occurred, reactions (9) – (11)



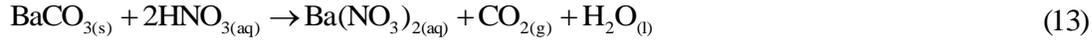
It is important to note that  $\text{BaZrO}_3$  is unstable in acidic gases at elevated temperatures.<sup>10</sup>  $\text{BaZrO}_3$  is highly reactive towards  $\text{SO}_3(\text{g})$  to form  $\text{BaSO}_4$  as a side product, reaction (12),



The decomposition reaction (8) was performed in a high flow of inert atmosphere in order to avoid formation of barium sulfate.

## 2 Deposition of BaO films

In order to synthesize BaO films the following procedure was developed. Appropriate amount of BaCO<sub>3</sub> was dissolved in aqueous HNO<sub>3</sub>, reaction (13). The resulting clear solution was evaporated at 90 °C. After carefully drying on the hot plate, crystalline solid is obtained as shown in reaction (13). The product is dissolved in deionized H<sub>2</sub>O giving a dilute solution (0.015 M) and mixed with citric acid (CA) 0.05 wt% of solution. This solution was used further. Note that CA is used to reduce surface tension for deposition of the solution on the ceramic surface.



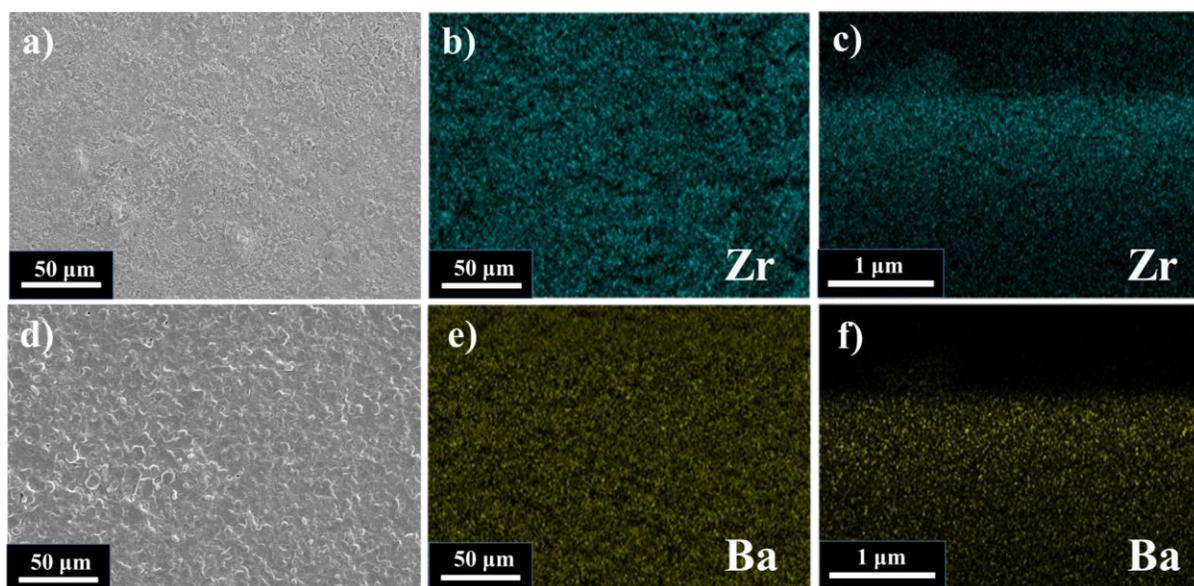
The necessary amount of Ba(NO<sub>3</sub>)<sub>2</sub> solution was drop casted on the surface of the BaZrO<sub>3</sub> pellet at 100 °C. The coated ceramic was carefully dried on the plate at 110 °C giving a dense and white layer of Ba(NO<sub>3</sub>)<sub>2</sub>. The coated pellets were further heat treated at 700 °C for 3 h in flowing N<sub>2</sub> in order to decompose nitrate according to reaction (14)



It is important to note that BaO is reactive towards CO<sub>2</sub> in air, and traces of BaCO<sub>3</sub> might occur upon cooling and exposure to ambient air.

## 3 Thin films of the tracers

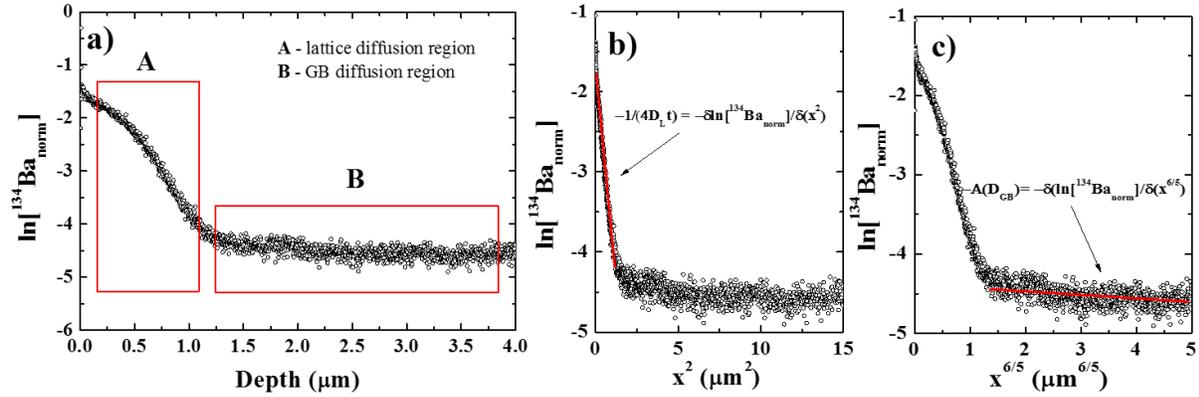
The homogeneous layers of BaO and ZrO<sub>2</sub> were characterized by EDS and the results are shown in Figure S1. The distribution of the main elements was recorded and filtered separately to give the representative and mono-elemental images. The mapping was performed with ~8 keV electron beam. The thickness of the layers varied 0.8–2 μm. The figure indicate limitation of the SEM equipment used in the thickness region ~1 μm. However, the differences in element concentration from surface to the bulk are obvious. The coated ceramics were used further.



**Figure S1.** Layers of  $\text{ZrO}_2$  (a, b, c) and  $\text{BaO}$  (d, e, f) on the surface of BZ: a) and d) – SEM images; b) and e) – EDS elemental mapping; c) and f) – EDS cross-section mapping.

#### 4 Fitting procedure of the tracer profiles

The lattice diffusion coefficient constant was evaluated from the slope of the logarithmic concentration versus  $x^2$  (Equation 4). The grain boundary diffusion coefficient was calculated from the shallow part of logarithmic concentration versus and  $x^{6/5}$  (Equation 5). The selected depth profile as a scheme for the fitting approach concerning the normalized distribution for  $^{134}\text{Ba}$  diffusion in BZ is given in Figure S2. The tracer penetration into the lattice  $<1 \mu\text{m}$  is shorter than the average grain size. The lattice diffusion constant was evaluated from the slope of the logarithmic concentration change versus  $x^2$  (see Figure S2b). The grain boundary diffusion coefficient was determined from the shallow part of logarithmic concentration versus and  $x^{6/5}$  (see Figure S2c). The diffusion coefficients for all the samples are summarized in Table S1.



**Figure S2.** Logarithmic concentration changes of  $^{134}\text{Ba}$  in BZ versus depth (a) and modified depth used for the fitting of lattice (b) and grain boundary (c) diffusion coefficients. The sample was annealed at 1050 °C for 35 h.

The critical parameters  $\alpha$  and  $\beta$  were extracted from  $D_L$  and  $D_{GB}$ , using the following equations

$$\alpha = \frac{s\delta}{2\sqrt{D_L t}} \quad (15)$$

$$\beta = \frac{s\delta D_{GB}}{2D_L \sqrt{D_L t}} \quad (16)$$

where,  $\delta=1$  nm;  $s=1$  and  $t$  is diffusion anneal time. The critical parameters  $\alpha$  and  $\beta$  are summarized in Table S1 for all the samples.  $\alpha$  and  $\beta$  represent the ratio of the bulk and grain-boundary diffusion to the effective diffusion coefficient. The estimated values for  $\alpha$  is in the range 0.01–0.03 for both tracers and are higher for  $^{96}\text{Zr}$  transport. The  $\beta$  values exceed 100 and are higher for  $^{134}\text{Ba}$  tracer diffusion. These values demonstrate that the requirements for determination of the grain boundary diffusion is fulfilled.<sup>29</sup>

## 5 Fitting of the tracer diffusion coefficients to the Arrhenius equation

The fitting of the Arrhenius equation to the experimental data for  $^{134}\text{Ba}$  and  $^{96}\text{Zr}$  diffusion in BZ are given in Table S1. The data demonstrate that the slope is less for grain boundaries than for the lattice.

**Table S1.** Experimental conditions for the thermal annealing, and lattice and grain boundary diffusion coefficients and the coefficients  $\alpha$  and  $\beta$  data for  $^{134}\text{Ba}$  and  $^{96}\text{Zr}$  diffusion in  $\text{BaZrO}_3$ .

Sample	Tracer	Time (h)	Temperature (°C)	$D_L$ ( $\text{cm}^2/\text{s}$ )	$D_{GB}$ ( $\text{cm}^2/\text{s}$ )	$\alpha$	$\beta$
t1-T1	$^{134}\text{Ba}$	90	1015	$2.78 \cdot 10^{-15}$	$1.44 \cdot 10^{-10}$	0.0017	$870 \pm 70$
t2-T2		30	1050	$4.94 \cdot 10^{-15}$	$1.43 \cdot 10^{-10}$	0.0020	$1000 \pm 140$
t3-T3		10	1100	$4.76 \cdot 10^{-14}$	$1.05 \cdot 10^{-9}$	0.0012	$270 \pm 20$
t4-T4		4	1150	$8.87 \cdot 10^{-14}$	$2.17 \cdot 10^{-9}$	0.0014	$350 \pm 20$
t5-T5		2	1200	$2.34 \cdot 10^{-13}$	$3.25 \cdot 10^{-9}$	0.0012	$1690 \pm 2$
t1-T1	$^{96}\text{Zr}$	90	1300	$9.64 \cdot 10^{-16}$	$3.26 \cdot 10^{-11}$	0.0028	$96 \pm 4$
t2-T2		35	1350	$7.33 \cdot 10^{-15}$	$1.45 \cdot 10^{-10}$	0.0023	$352 \pm 1$
t3-T3		10	1400	$1.36 \cdot 10^{-14}$	$2.37 \cdot 10^{-10}$	0.0018	$394 \pm 3$
t4-T4		4	1450	$2.14 \cdot 10^{-14}$	$4.68 \cdot 10^{-10}$	0.0028	$625 \pm 1$
t5-T5		2	1500	$5.95 \cdot 10^{-14}$	$8.21 \cdot 10^{-10}$	0.0024	$333 \pm 1$

**Table S2.** A summary of the fitting of the Arrhenius equation to the experimental data for both lattice and grain boundary diffusion of both Ba and Zr in polycrystalline BZ.

Tracer	Annealing conditions	Diffusion location	Adj. $R^2$	Intercept	Error	Slope	Error	D ( $\text{cm}^2 \text{s}^{-1}$ )	Error
$^{134}\text{Ba}$	1050 °C; 35 h	Lattice	0.982	-1.31	0.01	-3.02	0.02	$4.94 \times 10^{-15}$	$1 \times 10^{-15}$
		GB	0.868	-4.00	0.05	-0.36	0.02	$1.43 \times 10^{-10}$	$1 \times 10^{-10}$
$^{96}\text{Zr}$	1450 °C; 4 h	Lattice	0.995	-1.04	0.01	-0.81	0.01	$2.14 \times 10^{-14}$	$1 \times 10^{-14}$
		GB	0.995	-2.18	0.01	-0.27	0.01	$4.68 \times 10^{-10}$	$1 \times 10^{-10}$